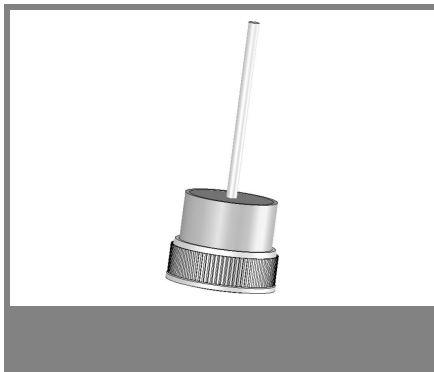


# BYP 25A05 ... BYP 25K6



Type	Wired to ANODE	Wired to CATHODE	Repetitive peak reverse voltage $V_{RRM}$ V	Surge peak reverse voltage $V_{RSM}$ V	Maximum forward voltage $T_j = 25\text{ }^\circ\text{C}$ $I_F = 25\text{ A}$ $V_F$ V
BYP 25	BYP 25A05	BYP 25K05	50	60	1,1
BYP 25	BYP 25A1	BYP 25K1	100	120	1,1
BYP 25	BYP 25A2	BYP 25K2	200	240	1,1
BYP 25	BYP 25A3	BYP 25K3	300	360	1,1
BYP 25	BYP 25A4	BYP 25K4	400	480	1,1
BYP 25	BYP 25A6	BYP 25K6	600	700	1,1

## Silicon Press-Fit-Diodes

### BYP 25A05...BYP 25K6

**Forward Current: 25 A**

**Reverse Voltage: 50 to 600 V**

Publish Data

### Features

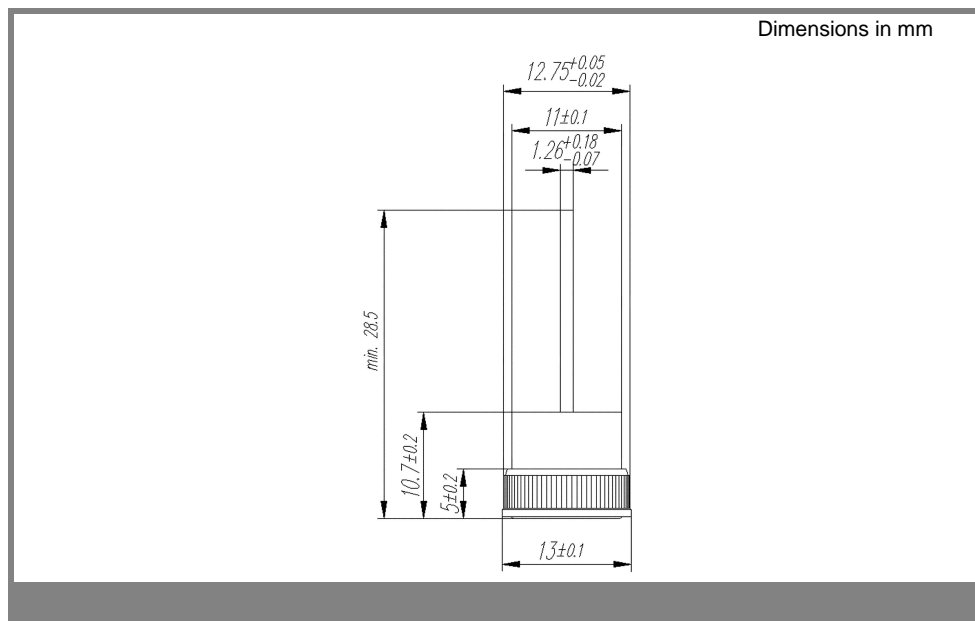
- max. solder temperature 260°C, max. 5s
- UL classification 94V-0
- Standard packaging: bulk

### Mechanical Data

- Weight approx. 8 g
- Metal press-fit case with plastic cover
- Terminals: plated terminals solderable per IEC 68-2-20
- Mounting position : any

Absolute Maximum Ratings		$T_c = 25\text{ }^\circ\text{C}$ , unless otherwise specified	
Symbol	Conditions	Values	Units
$I_{FAV}$	Max. averaged fwd. current, R-load, $T_c = 150\text{ }^\circ\text{C}$	25	A
$I_{FRM}$	Repetitive peak forward current $f > 15\text{ Hz}^{1)}$	90	A
$I_{FSM}$	Peak fwd. surge current 50 Hz half sinus-wave	270	A
$I^2t$	Rating for fusing, $t < 10\text{ ms}$	375	A <sup>2</sup> s
$R_{thA}$	Thermal resistance junction to case	1	K/W
$T_j$	Operating junction temperature	- 50 ... + 215	°C
$T_s$	Storage temperature	- 50 ... + 215	°C

Characteristics		$T_c = 25\text{ }^\circ\text{C}$ , unless otherwise specified	
Symbol	Conditions	Values	Units
$I_R$	Maximum leakage current, $T_A 25\text{ }^\circ\text{C}$ ; $V_R = V_{RRM}$	100	$\mu\text{A}$



# BYP 25A05 ... BYP 25K6

